



FFPF12UP20DN

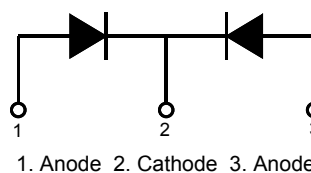
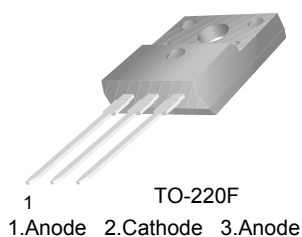
Ultrafast Recovery Power Rectifier

Features

- Ultrafast with Soft Recovery : < 35ns (@ $I_F = 6A$)
- High Reverse Voltage : $V_{RRM} = 200V$
- Enhanced Avalanche Energy Rated
- Planar Construction

Applications

- Output Rectifiers
- Switching Mode Power Supply
- Free-wheeling Diode
- Power Switching Circuits



Absolute Maximum Ratings

(per diode) $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	200	V
V_{RWM}	Working Peak Reverse Voltage	200	V
V_R	DC Blocking Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 120^\circ C$	6	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	5.0	$^\circ C/W$

Package Marking and Ordering Information

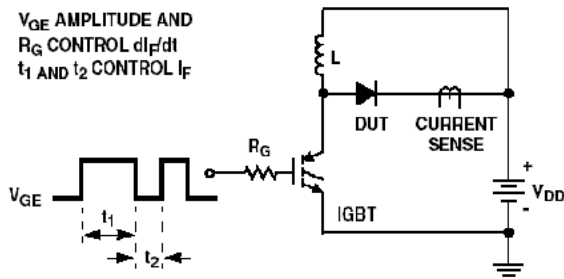
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F12UP20DN	FFPF12UP20DNTU	TO-220F	-	-	50

Electrical Characteristics (per diode) $T_C = 25^\circ\text{C}$ unless otherwise noted

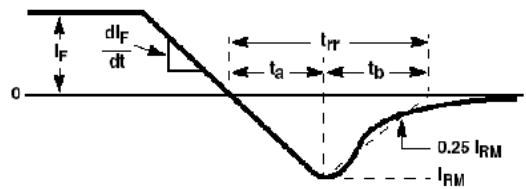
Symbol	Parameter	Min.	Typ.	Max.	Units	
V_{FM}^*	$I_F = 6\text{A}$ $I_F = 6\text{A}$	$T_C = 25^\circ\text{C}$	-	-	1.15	V
		$T_C = 100^\circ\text{C}$	-	-	1.0	V
I_{RM}^*	$V_R = 200\text{V}$ $V_R = 200\text{V}$	$T_C = 25^\circ\text{C}$	-	-	100	μA
		$T_C = 100^\circ\text{C}$	-	-	500	μA
t_{rr}	$I_F = 1\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 30\text{V}$ $I_F = 6\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 130\text{V}$	$T_C = 25^\circ\text{C}$	-	-	30	ns
		$T_C = 25^\circ\text{C}$	-	-	35	ns
t_a t_b Q_{rr}	$I_F = 6\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 130\text{V}$	$T_C = 25^\circ\text{C}$	-	12	-	ns
		$T_C = 25^\circ\text{C}$	-	12	-	ns
		$T_C = 25^\circ\text{C}$	-	24	-	nC
W_{AVL}	Avalanche Energy (L = 20mH)	10	-	-	mJ	

* Pulse Test: Pulse Width=300 μs , Duty Cycle=2%

Test Circuit and Waveforms

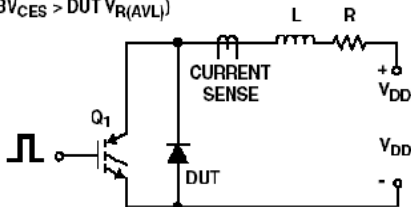


t_{rr} TEST CIRCUIT

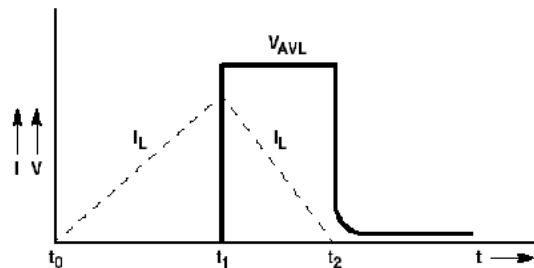


t_{rr} WAVEFORMS AND DEFINITIONS

- $I_{MAX} = 1\text{A}$
- $L = 20\text{mH}$
- $R < 0.1\Omega$
- $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
- $Q_1 = \text{IGBT (}BV_{CES} > \text{DUT } V_{R(AVL)}\text{)}$



AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop

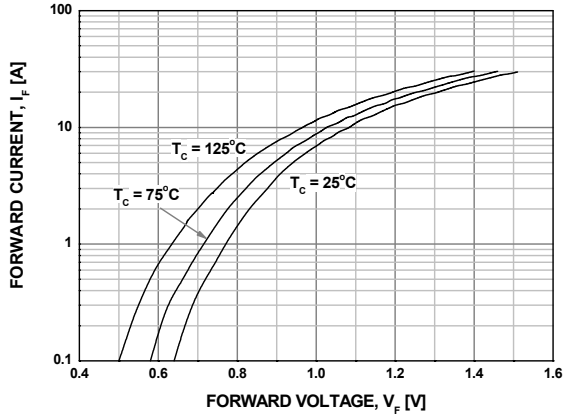


Figure 2. Typical Reverse Current

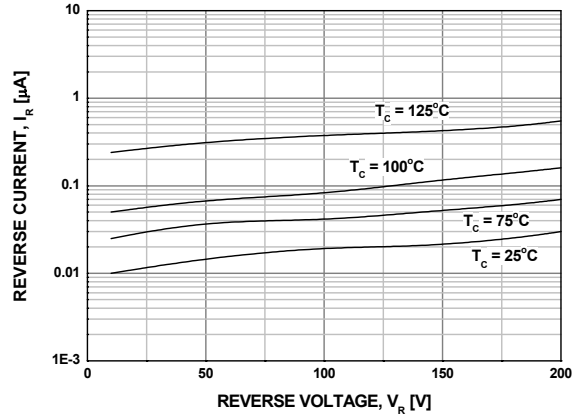


Figure 3. Typical Junction Capacitance

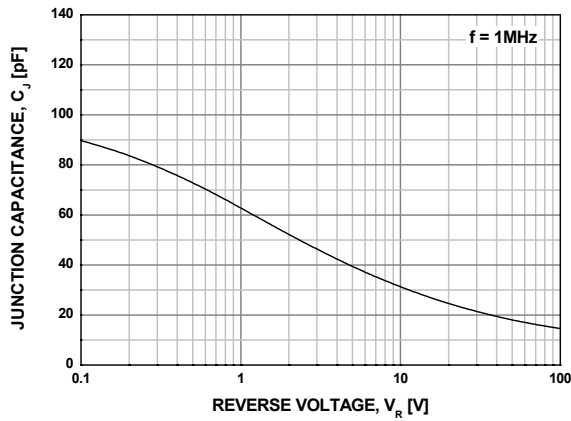


Figure 4. Typical Reverse Recovery Time

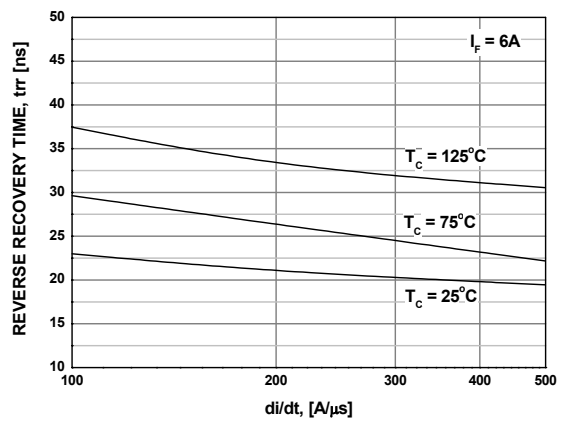


Figure 5. Typical Reverse Recovery Current

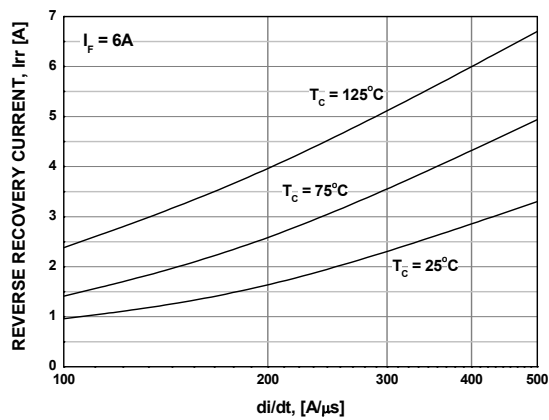
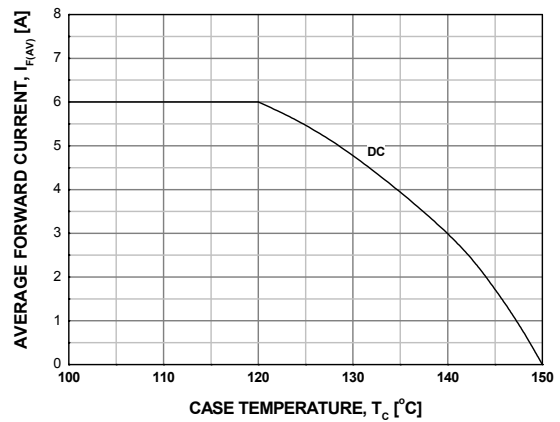
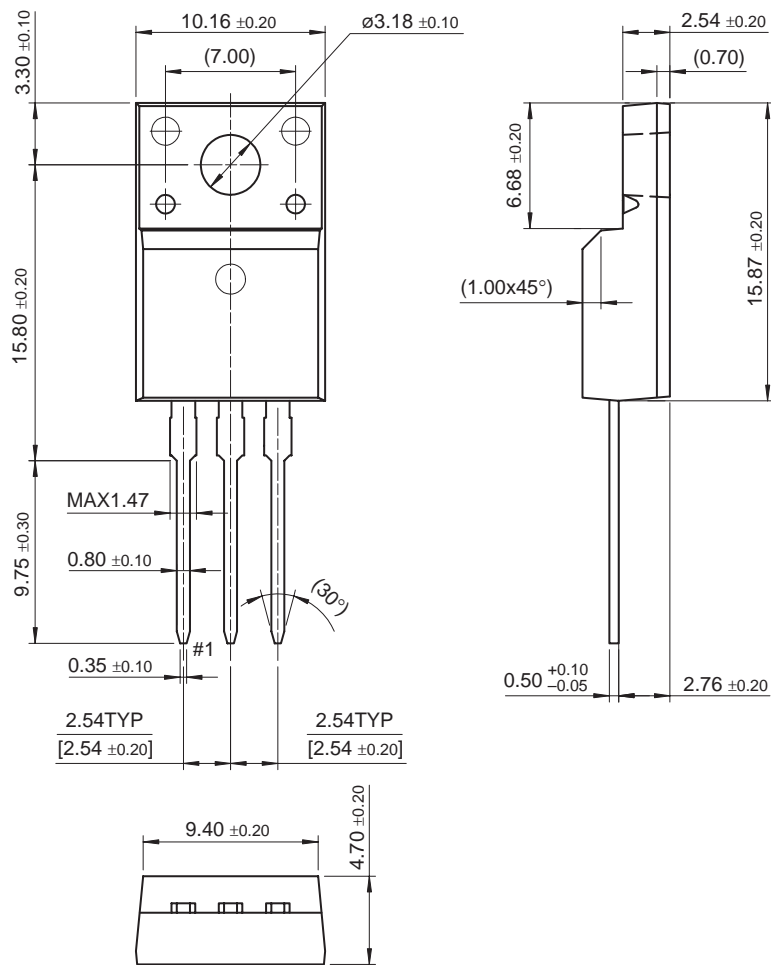


Figure 6. Forward Current Deration Curve



Package Demensions

TO-220F



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACE ^x TM	FAST [®]	ISOPLANAR TM	PowerEdge TM	SuperFET TM
ActiveArray TM	FAST ^r TM	LittleFET TM	PowerSaver TM	SuperSOT TM -3
Bottomless TM	FPS TM	MICROCOUPLER TM	PowerTrench [®]	SuperSOT TM -6
Build it Now TM	FRFET TM	MicroFET TM	QFET [®]	SuperSOT TM -8
CoolFET TM	GlobalOptoisolator TM	MicroPak TM	QS TM	SyncFET TM
CROSSVOLT TM	GTO TM	MICROWIRE TM	QT Optoelectronics TM	TCM TM
DOMET TM	HiSeC TM	MSX TM	Quiet Series TM	TinyLogic [®]
EcoSPARK TM	I ² C TM	MSXPro TM	RapidConfigure TM	TINYOPTO TM
E ² C ^{MOS} TM	<i>i-Lo</i> TM	OCX TM	RapidConnect TM	TruTranslation TM
EnSigna TM	ImpliedDisconnect TM	OCXPro TM	μ SerDes TM	UHC TM
FACT TM	IntelliMAX TM	OPTOLOGIC [®]	ScalarPump TM	UniFET TM
FACT Quiet Series TM		OPTOPLANAR TM	SILENT SWITCHER [®]	UltraFET [®]
Across the board. Around the world. TM		PACMAN TM	SMART START TM	VCX TM
The Power Franchise [®]		POP TM	SPM TM	Wire TM
Programmable Active Droop TM		Power247 TM	Stealth TM	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.